# onsemi

## **N-Channel JFET**

## 15 V, 6 to 32 mA, 38 mS, CP

## 2SK2394

#### SC-59-3 318BJ

### Features

- Large |yfs|
- Small C<sub>iss</sub>
- Small–Sized Package Permitting 2SK2394–Applied Sets to be Made Small Slim
- Ultralow Noise Figure
- This is a Pb-Free Device

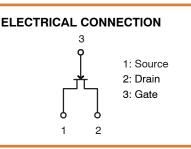
#### Applications

- AM Tuner RF Amplifier
- Low-Noise Amplifier

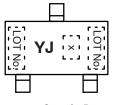
#### ABSOLUTE MAXIMUM RATINGS at $T_A$ = 25°C

Symbol	Parameter	Value	Unit	
V <sub>DSX</sub>	Drain-to-Source Voltage	15	V	
V <sub>GDS</sub>	Gate-to-Drain Voltage	-15	V	
۱ <sub>G</sub>	Gate Current	10	mA	
I <sub>D</sub>	Drain Current	50	mA	
PD	Allowable Power Dissipation	200	mW	
TJ	Junction Temperature	150	°C	
T <sub>stg</sub>	Storage Temperature	–55 to +150	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



#### MARKING DIAGRAM



= Specific Device Code x = 6 or 7

#### ORDERING INFORMATION

YJx

Device	Package	Shipping <sup>†</sup>
2SK2394-6-TB-E	SC–59–3 (Pb–Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

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#### 2SK2394

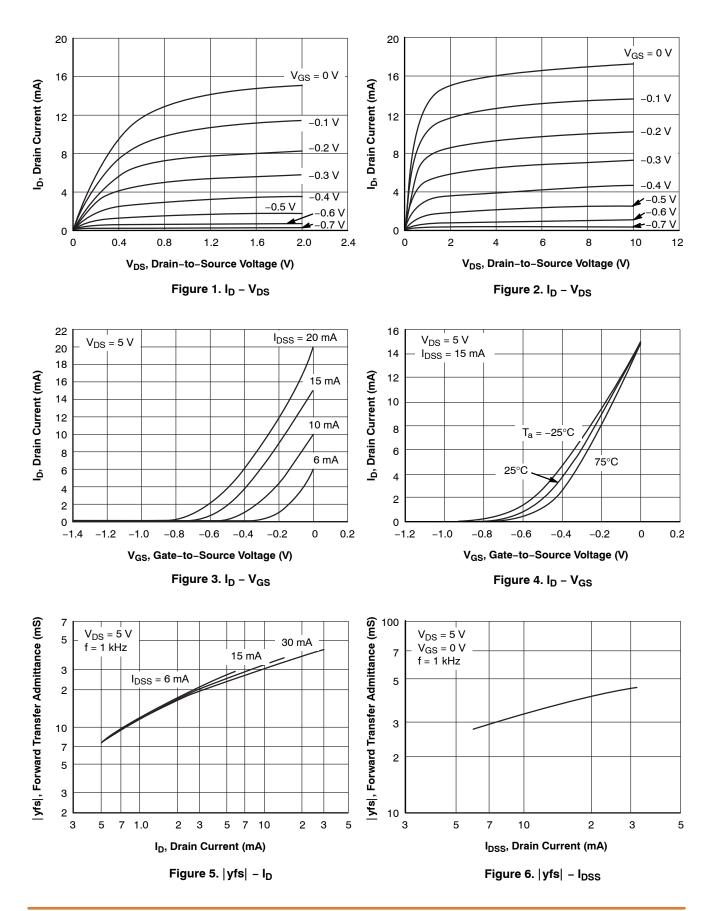
### **ELECTRICAL CHARACTERISTICS** at $T_{A}$ = 25°C

			Ratings			
Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
V <sub>(BR)GDS</sub>	Gate-to-Drain Breakdown Voltage	$I_{G} = -10 \text{ mA}, V_{DS} = 0 \text{ V}$	-15	-	_	V
I <sub>GSS</sub>	Gate Cutoff Current	$V_{GS} = -10 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$	-	-	-1.0	nA
V <sub>GS(off)</sub>	Cutoff Voltage	$V_{DS} = 5 \text{ V}, \text{ I}_{D} = 100 \ \mu\text{A}$	-0.3	-0.7	-1.0	V
I <sub>DSS</sub>	Drain Current	$V_{DS} = 5 \text{ V}, V_{GS} = 0 \text{ V}$	10	-	20	mA
yfs	Forward Transfer Admittance	$V_{DS}$ = 5 V, $V_{GS}$ = 0 V, f = 1 kHz	20	38	-	mS
C <sub>iss</sub>	Input Capacitance	$V_{DS}$ = 5 V, $V_{GS}$ = 0 V, f = 1 MHz	-	10.0	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	7	-	2.9	_	pF
NF	Noise Figure	$V_{DS}$ = 5 V, $R_g$ = 1 k $\Omega$ , $I_D$ = 1 mA, f = 1 kHz	-	1.0	-	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

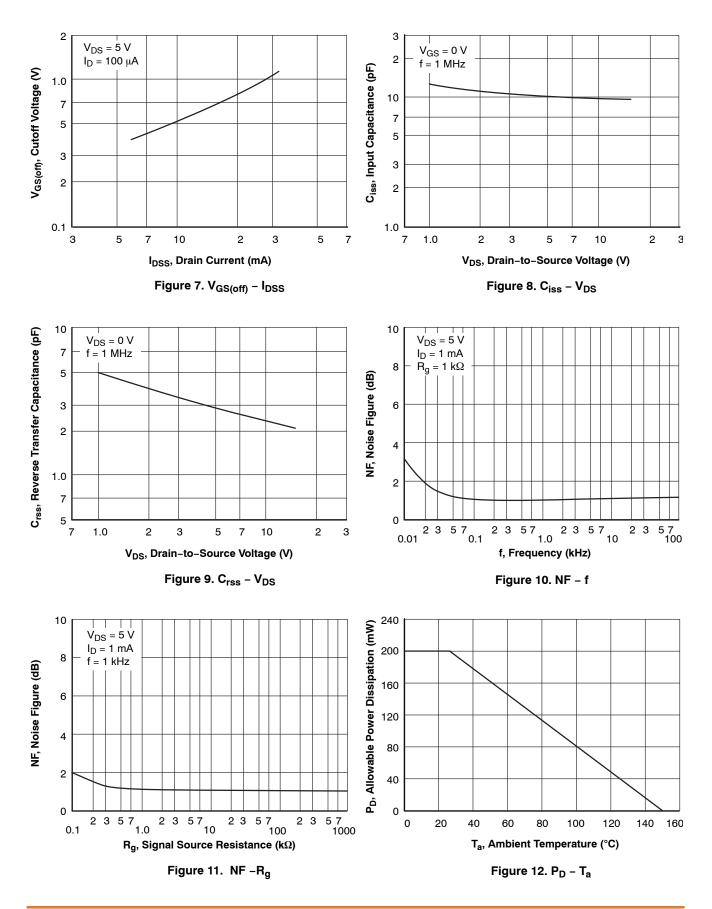
#### 2SK2394

#### **TYPICAL CHARACTERISTICS**

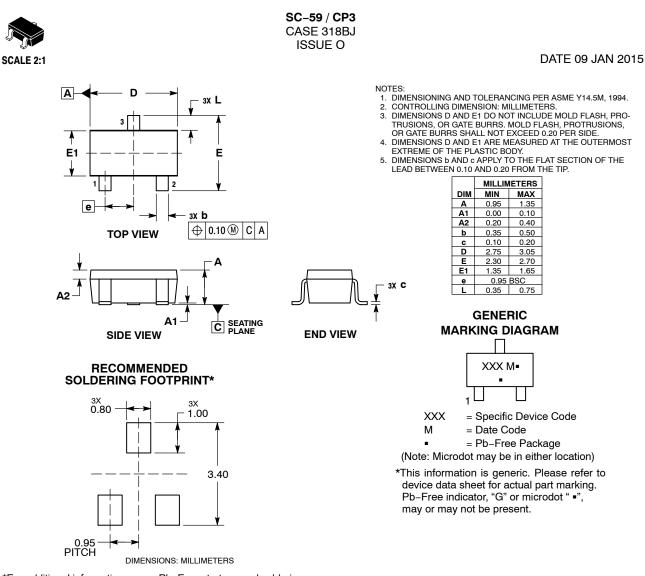


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#### TYPICAL CHARACTERISTICS (continued)







\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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